

KSC13003H

SemiHow
Know-How for Semiconductor

KSC13003H

Switch Mode series NPN silicon Power Transistor


- High voltage, high speed power switching
- Suitable for switching regulator, inverters motor controls

1.5 Amperes
NPN Silicon Power Transistor
20 Watts

Absolute Maximum Ratings $T_C=25^{\circ}\text{C}$ unless otherwise noted

CHARACTERISTICS	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	900	V
Collector-Emitter Voltage	V_{CEO}	530	V
Emitter-Base Voltage	V_{EBO}	9	V
Collector Current(DC)	I_C	1.5	A
Collector Current(Pulse)	I_{CP}	3	A
Base Current	I_B	0.75	A
Collector Dissipation($T_C=25^{\circ}\text{C}$)	P_C	20	W
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-65~150	$^{\circ}\text{C}$

TO-126
1. Base
2. Collector
3. Emitter



Electrical Characteristics $T_C=25^{\circ}\text{C}$ unless otherwise noted

CHARACTERISTICS	SYMBOL	Test Condition	Min	Typ.	Max	Unit
Collector-Emitter Breakdown Voltage	V_{CEO}	$I_C=5\text{mA}, I_B=0$	400			V
Emitter Cut-off Current	I_{EBO}	$V_{EB}=9\text{V}, I_C=0$			10	μA
*DC Current Gain	h_{FE1} h_{FE2}	$V_{CE}=2\text{V}, I_C=0.5\text{A}$ $V_{CE}=2\text{V}, I_C=1\text{A}$	9 5		40	
*Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=0.5\text{A}, I_B=0.1\text{A}$ $I_C=1\text{A}, I_B=0.25\text{A}$ $I_C=1.5\text{A}, I_B=0.5\text{A}$			0.5 1 3	V V V
*Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=0.5\text{A}, I_B=0.1\text{A}$ $I_C=1\text{A}, I_B=0.25\text{A}$			1 1.2	V V
Output Capacitance	C_{ob}	$V_{CB}=10\text{V}, f=0.1\text{MHz}$		21		pF
Current Gain Bandwidth Product	f_T	$V_{CE}=10\text{V}, I_C=0.1\text{A}$	4			MHz
Turn on Time	t_{on}	$V_{CC}=125\text{V}, I_C=2\text{A}$ $I_{B1}=0.2\text{A}, I_{B2}=-0.2\text{A}$ $R_L=125\Omega$			1.1	μs
Storage Time	t_{stg}		4.0	μs		
Fall Time	t_F		0.7	μs		

* Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

Note.

hFE1 Classification	R	20 ~ 30
	O	25 ~ 35
	Y	30 ~ 40

Package Mark information.

S YWW Z KSC13003H	S	SemiHow symbol
	YWW	Y; year code, WW; week code
	Z	hFE1 Classification

Typical Characteristics

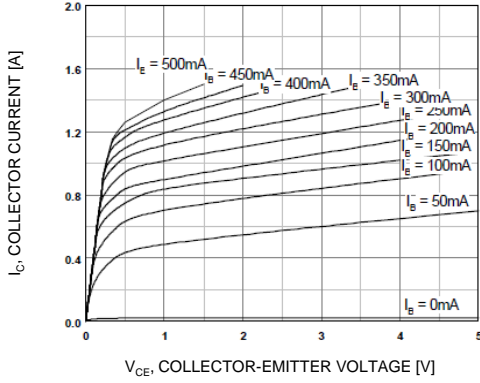


Figure 1. Static Characteristic

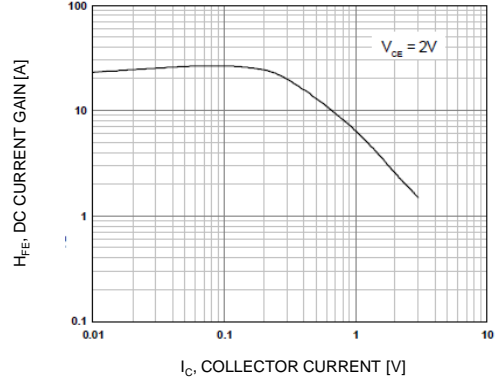


Figure 2. DC Current Gain

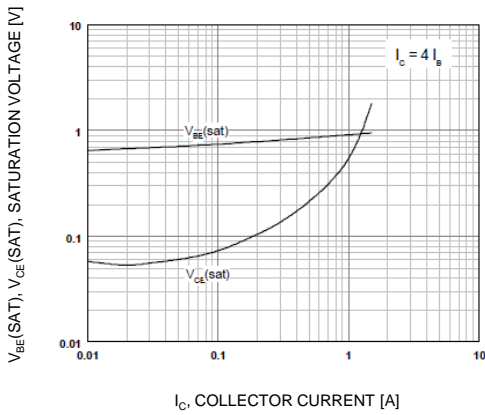


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

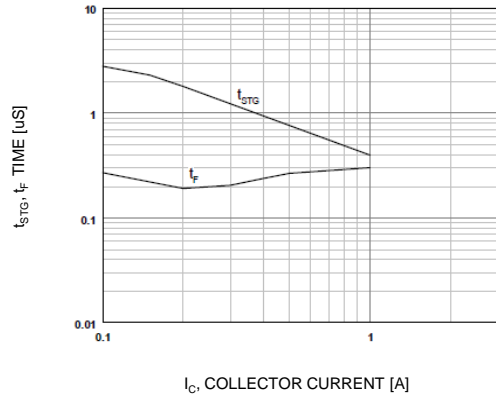


Figure 4. Switching Time

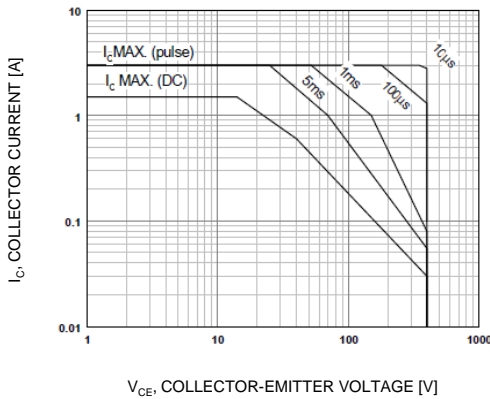


Figure 5. Safe Operating Area

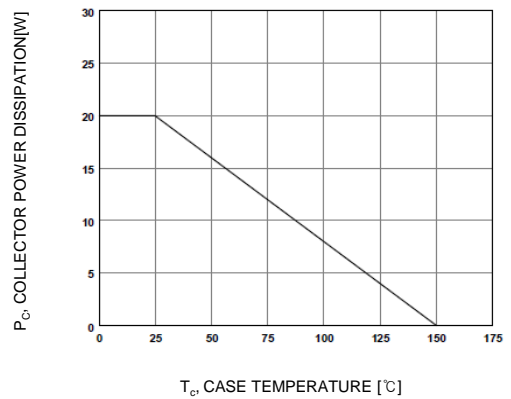
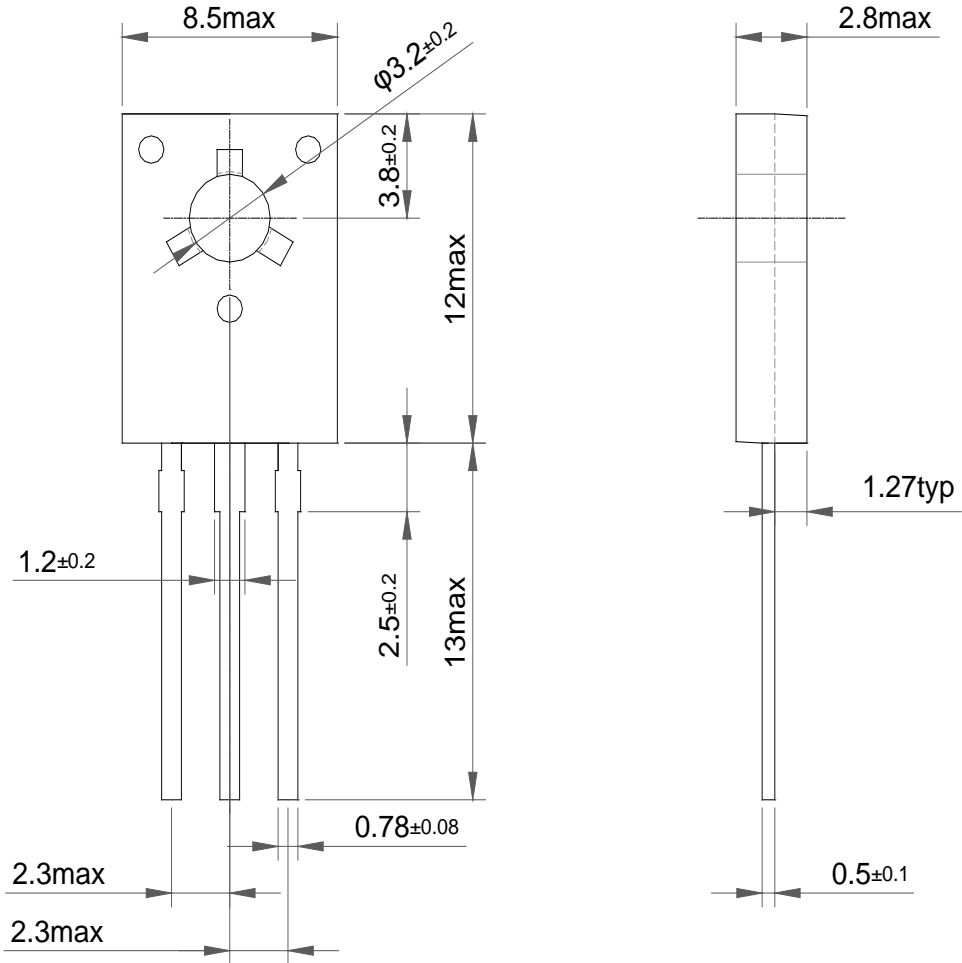


Figure 6. Power Derating

Package Dimension

TO-126



Dimensions in Millimeters